

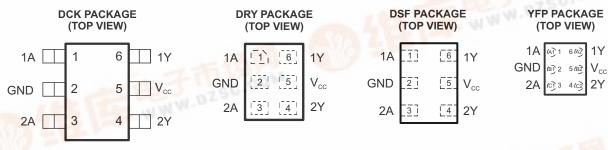
### LOW-POWER DUAL INVERTER GATE

Check for Samples: SN74AUP2G04

### **FEATURES**

- Available in the Texas Instruments NanoStar™ Package
- Low Static-Power Consumption:
   I<sub>CC</sub> = 0.9 μA Max
- Low Dynamic-Power Consumption:
   C<sub>pd</sub> = 4.3 pF Typ at 3.3 V
- Low Input Capacitance: C<sub>i</sub> = 1.5 pF Typ
- Low Noise: Overshoot and Undershoot
   <10% of V<sub>CC</sub>
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Wide Operating V<sub>CC</sub> Range of 0.8 V to 3.6 V

- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- t<sub>pd</sub> = 4.3 ns Max at 3.3 V
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)



N.C. - No internal connection

See mechanical drawings for dimensions.

### **DESCRIPTION/ORDERING INFORMATION**

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static- and dynamic-power consumption across the entire  $V_{CC}$  range of 0.8 V to 3.6 V, resulting in increased battery life (see Figure 1). This product also maintains excellent signal integrity (see the very low undershoot and overshoot characteristics shown in Figure 2).

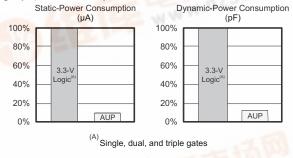


Figure 1. AUP - The Lowest-Power Family

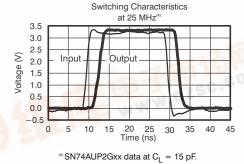


Figure 2. Excellent Signal Integrity

The SN74AUP2G04 performs the Boolean function  $Y = \overline{A}$  in positive logic.

**A** 

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Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



NanoStar<sup>™</sup> package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

### ORDERING INFORMATION(1)

T <sub>A</sub>	PACKAGE <sup>(2)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(3)</sup>
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YFP (Pb-free)	Reel of 3000	SN74AUP2G04YFPR	HC_
–40°C to 85°C	QFN – DRY	Reel of 5000	SN74AUP2G04DRYR	H4
	uQFN – DSF	Reel of 5000	SN74AUP2G04DSFR	H4
	SOT (SC-70) – DCK	Reel of 3000	SN74AUP2G04DCKR	H4_

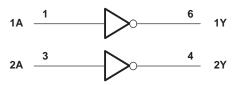
- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (3) DCK: The actual top-side marking has one additional character that designates the wafer fab/assembly site.

  YFP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, = Pb-free).

## FUNCTION TABLE (Each Inverter)

INPUT A	OUTPUT Y
Н	L
L	Н

### **LOGIC DIAGRAM (POSITIVE LOGIC)**





₩實情®N74AUP2C04"供应商

SCES747B - SEPTEMBER 2009-REVISED MARCH 2010

### ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V
VI	Input voltage range <sup>(2)</sup>		-0.5	4.6	V
Vo	Voltage range applied to any output in the h	high-impedance or power-off state (2)	-0.5	4.6	V
Vo	Output voltage range in the high or low stat	te <sup>(2)</sup>	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
Io	Continuous output current			±20	mA
	Continuous current through V <sub>CC</sub> or GND			±50	mA
		DCK package		252	
0	Declare the read in a dense (3)	DRY package	23		20.044
$\theta_{JA}$	Package thermal impedance (3)	DSF package		300	°C/W
		YFP package		132	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> The package thermal impedance is calculated in accordance with JESD 51-7.



### RECOMMENDED OPERATING CONDITIONS(1)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage		0.8	3.6	V	
		V <sub>CC</sub> = 0.8 V	V <sub>CC</sub>			
V	High level input valtage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$	$0.65 \times V_{CC}$		V	
$V_{IH}$	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.6		V	
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2			
		V <sub>CC</sub> = 0.8 V		0		
.,	Laur laural imput valtages	V <sub>CC</sub> = 1.1 V to 1.95 V		0.35 × V <sub>CC</sub>	V	
$V_{IL}$	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V	
		V <sub>CC</sub> = 3 V to 3.6 V		0.9		
VI	Input voltage		0	3.6	V	
Vo	Output voltage		0	V <sub>CC</sub>	V	
		V <sub>CC</sub> = 0.8 V		-20	μΑ	
	High level autout average	V <sub>CC</sub> = 1.1 V		-1.1		
		V <sub>CC</sub> = 1.4 V		-1.7		
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 1.65		-1.9	mA	
		$V_{CC} = 2.3 \text{ V}$		-3.1		
		$V_{CC} = 3 V$		-4		
		V <sub>CC</sub> = 0.8 V		20	μΑ	
		$V_{CC} = 1.1 \text{ V}$		1.1		
	Low lovel output ourrent	$V_{CC} = 1.4 \text{ V}$	1.7			
l <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 1.65 V		1.9		
		$V_{CC} = 2.3 \text{ V}$				
		V <sub>CC</sub> = 3 V				
Δt/Δν	Input transition rise or fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V		200	ns/V	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C	

<sup>(1)</sup> All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow of Floating CMOS Inputs, literature number SCBA004.



### **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	V	T <sub>A</sub>	= 25°C		$T_A = -40^{\circ}C$	to 85°C	LINUT	
PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	UNIT	
	I <sub>OH</sub> = -20 μA	0.8 V to 3.6 V	V <sub>CC</sub> - 0.1			V <sub>CC</sub> - 0.1			
	I <sub>OH</sub> = -1.1 mA	1.1 V	0.75 × V <sub>CC</sub>			0.7 × V <sub>CC</sub>			
	I <sub>OH</sub> = -1.7 mA	1.4 V	1.11			1.03			
V	I <sub>OH</sub> = -1.9 mA	1.65 V	1.32			1.3		V	
V <sub>OH</sub>	I <sub>OH</sub> = -2.3 mA	221/	2.05			1.97		V	
	$I_{OH} = -3.1 \text{ mA}$	2.3 V	1.9			1.85			
	I <sub>OH</sub> = -2.7 mA	2.1/	2.72			2.67			
	I <sub>OH</sub> = -4 mA	3 V	2.6			2.55			
	I <sub>OL</sub> = 20 μA	0.8 V to 3.6 V			0.1		0.1		
	I <sub>OL</sub> = 1.1 mA	1.1 V		0.3	× V <sub>CC</sub>		0.3 × V <sub>CC</sub>		
	I <sub>OL</sub> = 1.7 mA	1.4 V			0.31		0.37		
	I <sub>OL</sub> = 1.9 mA	1.65 V			0.31		0.35	V	
$V_{OL}$	I <sub>OL</sub> = 2.3 mA	221/			0.31		0.33	V	
	I <sub>OL</sub> = 3.1 mA	2.3 V			0.44		0.45		
	I <sub>OL</sub> = 2.7 mA	2.1/			0.31		0.33		
	I <sub>OL</sub> = 4 mA	3 V			0.44		0.45		
I <sub>I</sub> A or B input	$V_I = GND \text{ to } 3.6 \text{ V}$	0 V to 3.6 V			0.1		0.5	μΑ	
I <sub>off</sub>	$V_I$ or $V_O = 0 V$ to 3.6 V	0 V			0.2		0.6	μΑ	
Δl <sub>off</sub>	$V_I$ or $V_O = 0$ V to 3.6 V	0 V to 0.2 V			0.2		0.6	μΑ	
I <sub>CC</sub>	$V_I = GND \text{ or } (V_{CC} \text{ to } 3.6 \text{ V}),$ $I_O = 0$	0.8 V to 3.6 V			0.5		0.9	μА	
ΔI <sub>CC</sub>	$V_I = V_{CC} - 0.6 V^{(1)}, I_O = 0$	3.3 V			40		50	μА	
0	V V as CND	0 V		1.5					
C <sub>i</sub>	$V_I = V_{CC}$ or GND	3.6 V		1.5				pF	
Co	V <sub>O</sub> = GND	0 V		3				pF	

<sup>(1)</sup> One input at  $V_{CC}$  – 0.6 V, other input at  $V_{CC}$  or GND.

### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range,  $C_L = 5 pF$  (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	T,	<sub>λ</sub> = 25°C		$T_A = -40$ °C t	o 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	UNII
			0.8 V		18				
			1.2 V ± 0.1 V	2.6	7.3	12.8	2.1	15.6	
	A or B	Y	1.5 V ± 0.1 V	1.4	5.2	8.7	0.9	10.3	20
t <sub>pd</sub>	AUID	ľ	1.8 V ± 0.15 V	1	4.2	6.6	0.5	8.2	ns
			2.5 V ± 0.2 V	1	3	4.4	0.5	5.5	
			3.3 V ± 0.3 V	1	2.4	3.5	0.5	4.3	

Product Folder Link(s): SN74AUP2G04



### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range,  $C_L = 10 \text{ pF}$  (unless otherwise noted) (see Figure 3 and Figure 4)

DADAMETED	FROM	то	V	T,	<sub>λ</sub> = 25°C	;	T <sub>A</sub> = -40°C t	o 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	UNIT
		0.8 V		21					
			1.2 V ± 0.1 V	1.5	8.5	14.7	1	17.2	
	A or D	V	1.5 V ± 0.1 V	1	6.2	10	0.5	11.3	
t <sub>pd</sub>	A or B	Y	1.8 V ± 0.15 V	1	5	7.7	0.5	9	ns
			2.5 V ± 0.2 V	1	3.6	5.2	0.5	6.1	
			3.3 V ± 0.3 V	1	2.9	4.2	0.5	4.7	

### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range,  $C_L = 15 \text{ pF}$  (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	T,	4 = 25°C	;	T <sub>A</sub> = -40°C t	o 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V <sub>CC</sub>	MIN	TYP	MAX	MIN	MAX	UNII
		0.8 V		24					
			1.2 V ± 0.1 V	3.6	9.9	16.3	3.1	19.9	
	A or B		1.5 V ± 0.1 V	2.3	7.2	11.1	1.8	13.2	20
t <sub>pd</sub>	AOIB	Ť	1.8 V ± 0.15 V	1.6	5.8	8.7	1.1	10.6	ns
			2.5 V ± 0.2 V	1	4.3	5.9	0.5	7.3	
			$3.3 \text{ V} \pm 0.3 \text{ V}$	1	3.4	4.8	0.5	5.9	

### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range,  $C_L = 30 \text{ pF}$  (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	T	_ = 25°C	;	$T_A = -40^{\circ}C$ to	85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V <sub>CC</sub>	MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		32.8				
		Y	1.2 V ± 0.1 V	4.9	13.1	20.9	4.4	25.5	
	A or B		1.5 V ± 0.1 V	3.4	9.5	14.2	2.9	16.9	
t <sub>pd</sub>	AUID		1.8 V ± 0.15 V	2.5	7.7	11	2	13.5	ns
			2.5 V ± 0.2 V	1.8	5.7	7.6	1.3	9.4	
			$3.3 \text{ V} \pm 0.3 \text{ V}$	1.5	4.7	6.2	1	7.5	

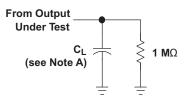
### **OPERATING CHARACTERISTICS**

 $T_{\Delta} = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	TYP	UNIT
			V 8.0	4	-
			1.2 V ± 0.1 V	4	
<u> </u>	Power discination canacitance	f = 10 MHz	1.5 V ± 0.1 V	4	
C <sub>pd</sub>	Power dissipation capacitance	I = IO MINZ	1.8 V ± 0.15 V	4	pF
			2.5 V ± 0.2 V	4.1	
			3.3 V ± 0.3 V	4.3	

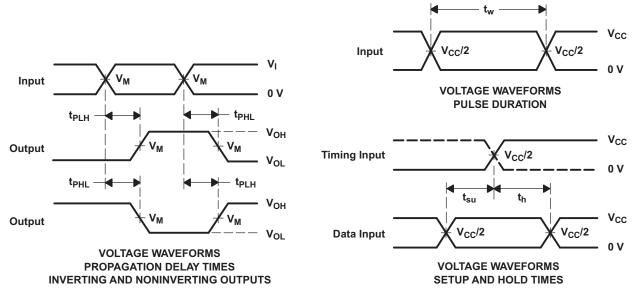


# PARAMETER MEASUREMENT INFORMATION (Propagation Delays, Setup and Hold Times, and Pulse Width)



**LOAD CIRCUIT** 

	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V ± 0.1 V	V <sub>CC</sub> = 1.5 V ± 0.1 V	V <sub>CC</sub> = 1.8 V ± 0.15 V	V <sub>CC</sub> = 2.5 V ± 0.2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V
$egin{array}{c} \mathbf{C_L} \\ \mathbf{V_M} \\ \mathbf{V_I} \end{array}$	5, 10, 15, 30 pF V <sub>CC</sub> /2 V <sub>CC</sub>	5, 10, 15, 30 pF V <sub>CC</sub> /2 V <sub>CC</sub>	5, 10, 15, 30 pF V <sub>CC</sub> /2 V <sub>CC</sub>	5, 10, 15, 30 pF V <sub>CC</sub> /2 V <sub>CC</sub>	5, 10, 15, 30 pF V <sub>CC</sub> /2 V <sub>CC</sub>	5, 10, 15, 30 pF V <sub>CC</sub> /2 V <sub>CC</sub>

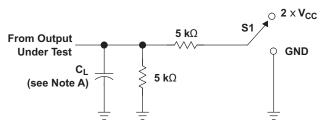


- C<sub>L</sub> includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ , for propagation delays  $t_t/t_f = 3$  ns, for setup and hold times and pulse width  $t_t/t_f = 1.2$  ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.
- F. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



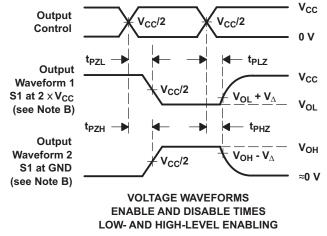
## PARAMETER MEASUREMENT INFORMATION (Enable and Disable Times)



TEST	<b>S1</b>
t <sub>PLZ</sub> /t <sub>PZL</sub>	2 × V <sub>CC</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

LOAD CIRCUIT

	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V ± 0.1 V	V <sub>CC</sub> = 1.5 V ± 0.1 V	V <sub>CC</sub> = 1.8 V ± 0.15 V	V <sub>CC</sub> = 2.5 V ± 0.2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V
CL	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
<b>V</b> <sub>M</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2
VI	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>
$oldsymbol{V}_{\!\Delta}$	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f/t_f = 3$  ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms



### PACKA

#### **PACKAGING INFORMATION**

www.ti.com

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Pe
SN74AUP2G04DCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260
SN74AUP2G04DRYR	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260
SN74AUP2G04DSFR	ACTIVE	SON	DSF	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260
SN74AUP2G04YFPR	ACTIVE	DSBGA	YFP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260

<sup>&</sup>lt;sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retard in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate in continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical at TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Cu

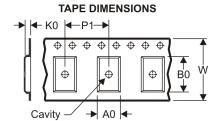


查询"SN74AUP2G04"供应商

18-Nov-2010

### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

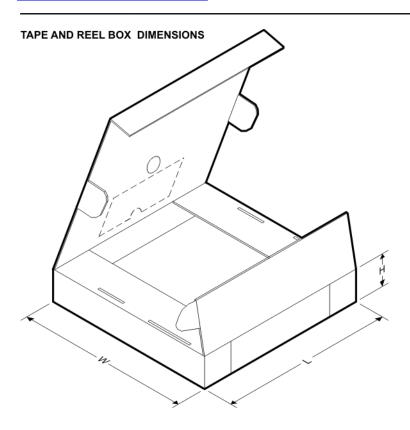


\*All dimensions are nominal

Device	_	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP2G04DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74AUP2G04DRYR	SON	DRY	6	5000	180.0	8.4	1.25	1.6	0.7	4.0	8.0	Q1
SN74AUP2G04DSFR	SON	DSF	6	5000	180.0	8.4	1.16	1.16	0.63	4.0	8.0	Q2
SN74AUP2G04YFPR	DSBGA	YFP	6	3000	178.0	9.2	0.89	1.29	0.62	4.0	8.0	Q1

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18-Nov-2010



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP2G04DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
SN74AUP2G04DRYR	SON	DRY	6	5000	202.0	201.0	28.0
SN74AUP2G04DSFR	SON	DSF	6	5000	202.0	201.0	28.0
SN74AUP2G04YFPR	DSBGA	YFP	6	3000	220.0	220.0	35.0

## DCK (R-PDSO-G6)

### PLASTIC SMALL-OUTLINE PACKAGE

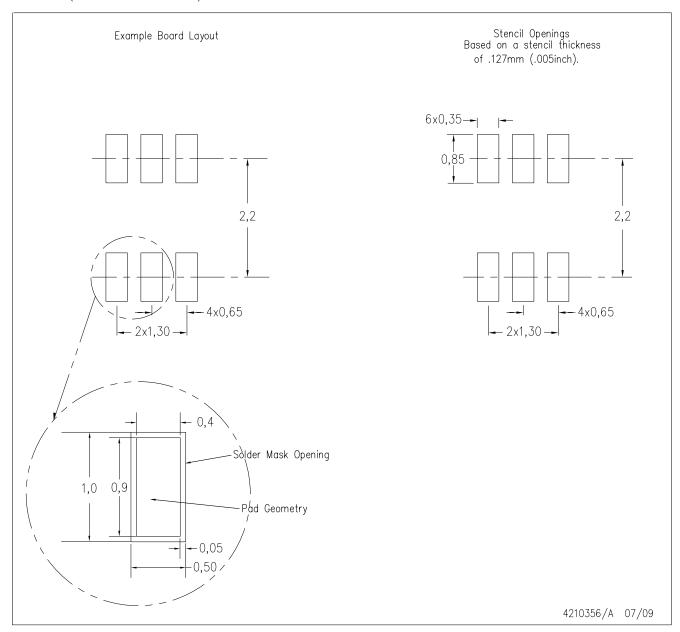


NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AB.



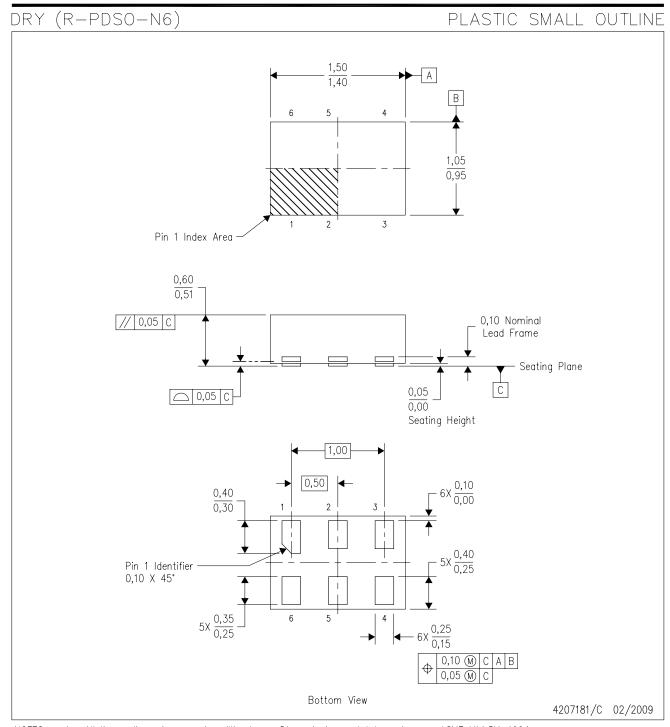
## DCK (R-PDSO-G6)



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

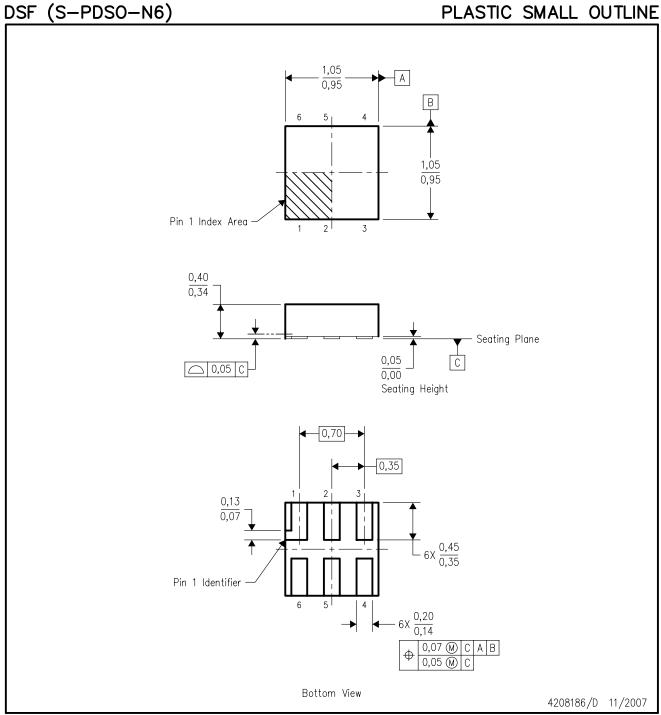




NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. SON (Small Outline No-Lead) package configuration.
- D. This package complies to JEDEC MO-287 variation UFAD.



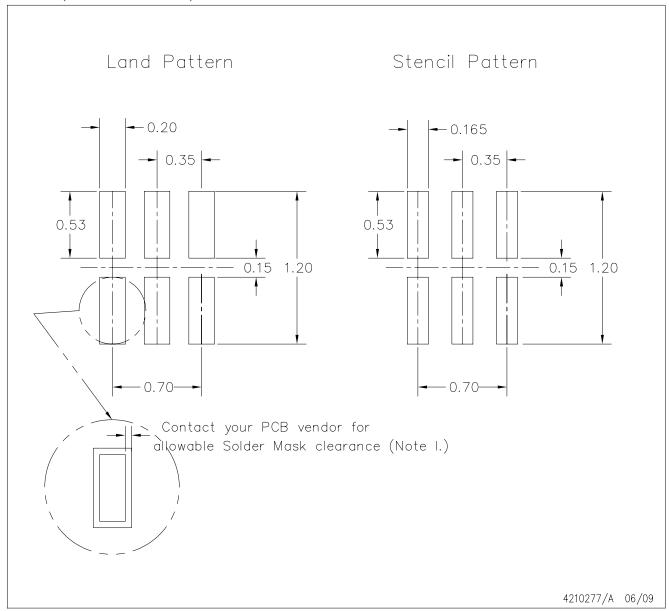


NOTES: All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
  C. SON (Small Outline No-Lead) package configuration.
  D. This package complies to JEDEC MO-287 variation X2AAF.



## DSF (S-PDSO-N6)

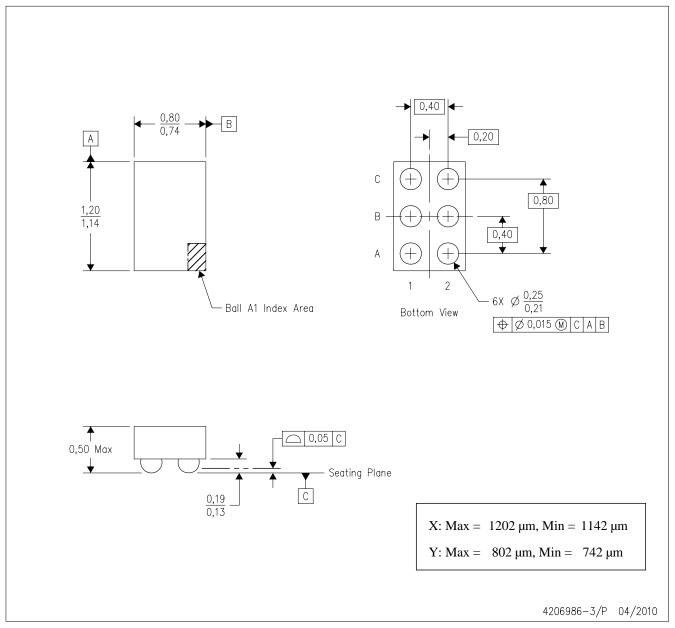


- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads. If 2 mil solder mask is outside PCB vendor capability, it is advised to omit solder mask.
  - E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
  - F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - G. Over-printing land for acceptable area ratio is not viable due to land width and bridging potential. Customer may further reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.
  - H. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
  - I. Component placement force should be minimized to prevent excessive paste block deformation.



YFP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This is a Pb-free solder ball design.

NanoFree is a trademark of Texas Instruments.



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